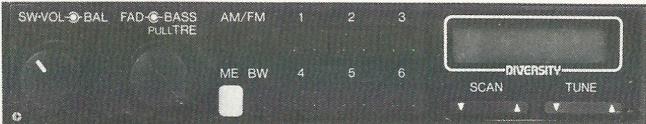


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Service Manual

Published by Service Administration Section



MAZDA Automobile Genuine Electronic Tuner Model RT-9071A

SPECIFICATIONS:

Circuit system:	Superheterodyne
Tuning system:	Electronic tuning
Receive range:	AM 531kHz to 1,602kHz FM 87.5MHz to 107.9MHz
Intermediate frequency:	AM 450kHz FM 10.7MHz
Quieting sensitivity:	AM Less than 33dB (at 20dB S/N) FM Less than 15dB (at 30dB S/N)
Selectivity:	AM More than 35dB (at ± 9 kHz detune)
Separation:	AM More than 15dB FM More than 20dB
Fidelity: (Bass, Treble=flat) (NARROW)	AM 100Hz -3 ± 3 dB 400Hz 0dB 4kHz -14 ± 5 dB FM 100Hz 1 ± 3 dB 1kHz 0dB 7kHz -21 ± 5 dB
Auto tuning stop sensitivity:	AM DX 27dB to 43dB LO 47dB to 67dB FM DX 27dB to 39dB
Load impedance:	10k Ω
Output level:	75mV ± 3 dB
Power supply voltage:	DC 13.2V (10.8V to 15.6V) Negative ground

Current consumption:

Less than 3A

(at max. output)

Dimensions:	Width 180mm
	Height 35mm
	Depth 160mm

Weight: 950g

COMPONENTS:

● RT-9071A-A	Main unit	1
● RT-9071A-B	Main unit	1
● UT-854A-02		
ET-386A-51	POWER AMP	1
ET-386I-51	POWER AMP	1
ET-597A-02	EQUALIZER	1
RT-8052A-B	CAR STEREO	1
RT-9071A-A	CAR RADIO	1
● UT-854A-03		
ET-386A-51	POWER AMP	1
ET-386I-51	POWER AMP	1
ET-597A-02	EQUALIZER	1
PT-8052A-B	CAR STEREO	1
RT-9071A-B	CAR RADIO	1

■ADJUSTMENTS:

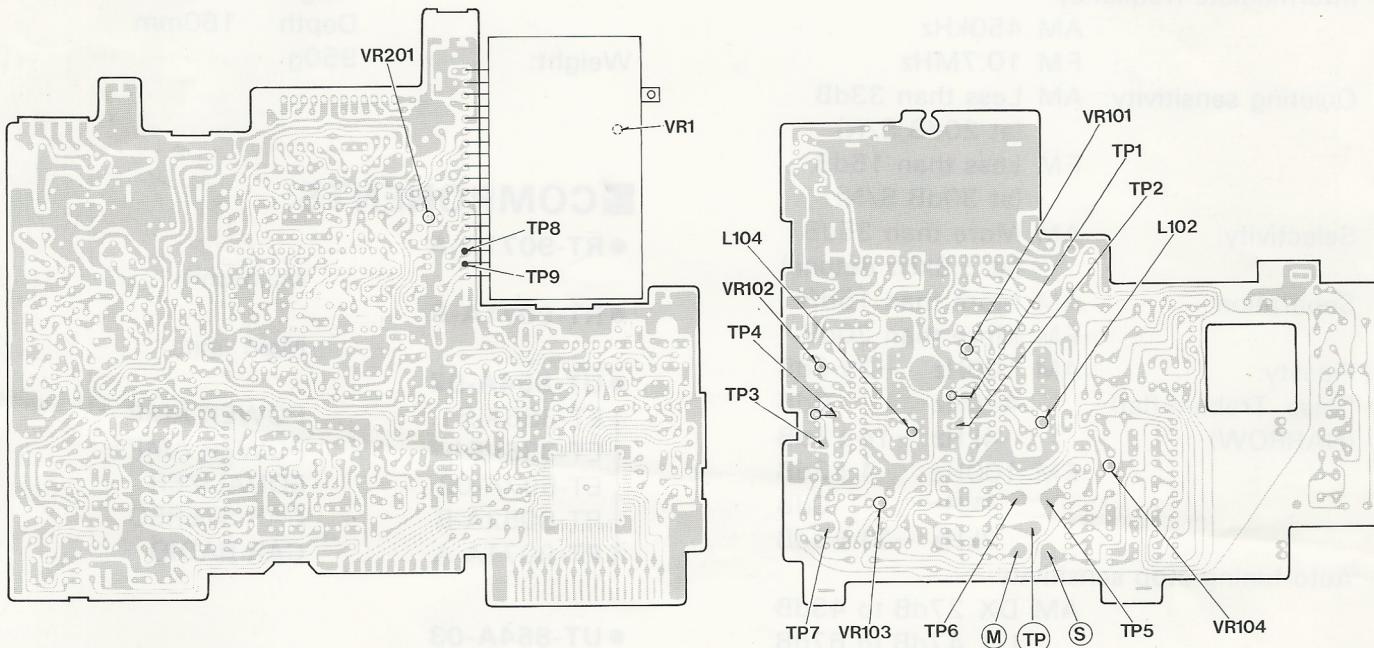
AM

Item	Adjustment	Measuring Instrument
Stop Sensitivity	1) Set the frequency to 999kHz and adjust the stop sensitivity to the specified level: Stop Sensitivity DX 35dB Adjustable VOL VR201	SG Milli-volt meter
Decoder Input	1) Connect the milli-volt meter to TP8. (TP9) 2) Set SG to 999kHz, 74dB. 3) Adjust the reading of milli-volt meter to $100\text{mV} \pm 5\text{mV}$ by VR1. (inside the tuner pack)	SG Milli-volt meter

FM

Item	Adjustment	Measuring Instrument
OV Adjustment	(MAIN) 1) Connect the digital voltmeter to TP3 and TP4. 2) Input the non-modulated 98.1MHz/55dB signal and adjust the reading of digital voltmeter to $0 \pm 20\text{mV}$ by L104. (SUB) 1) Connect the digital voltmeter to TP1 and TP2. 2) Follow the same adjustment steps as MAIN above. (L102)	SG Digital voltmeter
IF Level	(MAIN) 1) Connect the digital voltmeter to TP6. 2) Input the 98.1MHz frequency at 15dB and adjust the level to $0.63 \pm 0.1\text{V}$ by VR102. (SUB) 1) Connect the digital voltmeter to TP5. 2) Adjust the level by VR101 similar to MAIN.	SG Digital voltmeter
SASC	1) Set SG to 98.1MHz and input the 30%-modulated frequency 7kHz, 65dB. 2) Adjust the SASC outputs evenly to -1dB by VR104 when the SG output is set to 40dB.	SG Milli-volt meter
Stop Sensitivity	1) Tuner at 98.1MHz, input a 33dB non-modulated SSG signal. 2) Adjust VR103 so that the voltage of the TP7 is less than $0.7 \pm 0.2\text{V}$	SG Milli-volt meter

●ADJUSTMENT POINT



MAIN CHANNEL/SUB CHANNEL switching

- (1) It can be switched to the main channel by shorting **TP** & **M**
- (2) It can be switched to the sub channel by shorting **TP** & **S**

TK15021	051-0772-00	Analog Switch	P47
NJM2073D	051-0774-00	Dual Low Voltage Power Amp.	P31
NJM2904S	051-0285-54	Dual OP Amp.	P39
MPX-NC-H	051-0632-01	MPX with Noise Canceller for FM	P10
μ PD1708AG(A)903	051-0713-04	(051-0713-04 is modified from 051-0713-02)	P60

MC13020P 051-0630-00 MOTOROLA CQUAM® AM STEREO MC13020P 051-0630-01 DECODER

NOTE : 051-0630-01 is useful instead of 051-0630-00.

This circuit is a complete one-chip full-feature AM stereo decoding and pilot detection system. It employs full-wave envelope signal detection at all times for the L+R signal, and decodes L-R signals only in the presence of valid stereo transmission.

- No Adjustments, No Coils
- Few Peripheral Components
- True Full-Wave Envelope Detection for L+R
- PLL Detection for L-R
- 25Hz Pilot Presence Required To Receive L-R
- Pilot Acquisition Time 300ms For Strong Signals, Time Extended For Noise Conditions To Prevent "Falsing"
- Internal Level Detector Can Be Used As AGC Source

MAXIMUM RATINGS

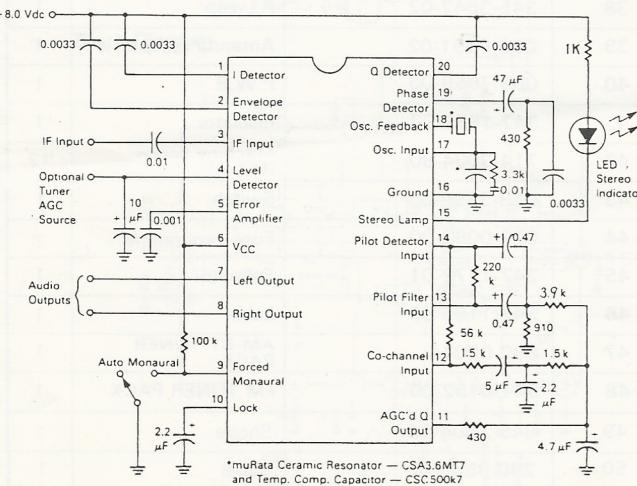
Rating	Symbol	Value	Unit
Supply Voltage	V _{CC}	14	Vdc
Pilot Lamp Current, Pin 15		50	mAdc
Operating Temperature	T _A	-40 to +85	°C
Storage Temperature	T _{stg}	-65 to +150	°C
Junction Temperature	T _{J(max)}	150	°C
Power Dissipation Derate above 25°C	P _D	1.25 10	W mW/°C

ELECTRICAL CHARACTERISTICS

(V_{CC}=8.0Vdc, T_A=25°C, Input Signal=200mVRMS Unmodulated Carrier, Circuit Of Figure 1 Unless Otherwise Noted.)

Characteristic	Min	Typ	Max	Unit
Power Supply Operating Range	—	6.0 ~ 12.0	—	Vdc
Supply Line Current Drain, Pin 6	20	30	40	mAdc
Input Signal Level, Unmodulated, Pin 3, for Full Operation	100	200	357	mVRMS
Audio Output Level, 50% Modulation, L only or R only	160	220	280	mVRMS
Audio Output Level, 50% Modulation, Monoaural	80	110	140	mVRMS
Output THD, 50% Modulation, Monoaural Stereo	0.5	+ 0.8	%	
Output THD, 50% Modulation, Monoaural Stereo	1.0	+ 1.5	%	
Channel Separation, L only or R only, 50% Modulation	+ 22	30	—	dB
Pilot Acquisition Time VCO locked, after release of forced monoaural	—	300	—	ms
Input Impedance	R _{in} C _{in}	20 6.0	—	kΩ pF
Output Impedance	—	100	150	Ω
Level Detector Filter Voltage, Pin 4, 200 mVRMS Signal	1.4 2.5	1.7 —	2.0	Vdc
Lock Detector Filter Voltage, Pin 10 In Lock Out of Lock	—	7.8 0.8	—	Vdc
Force to Monoaural, Pin 9, Pull Down for Monoaural Mode	2.0	2.5	—	Vdc
Force to Monoaural, Pin 9, Pull Up for Automatic Mode	—	0.15	1.0	μA
Force to Monoaural, Pin 9, Pull Up for Automatic Mode	—	3.5	3.7	Vdc
Force to Monoaural, Pin 9, Pull Up for Automatic Mode	—	< 0.001	1.0	μA

Fig. 1 – TYPICAL APPLICATION



*muRata Ceramic Resonator — CSA3.6MT7
and Temp. Comp. Capacitor — CSC500kT

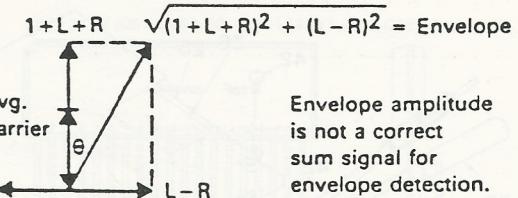
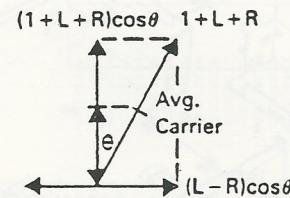
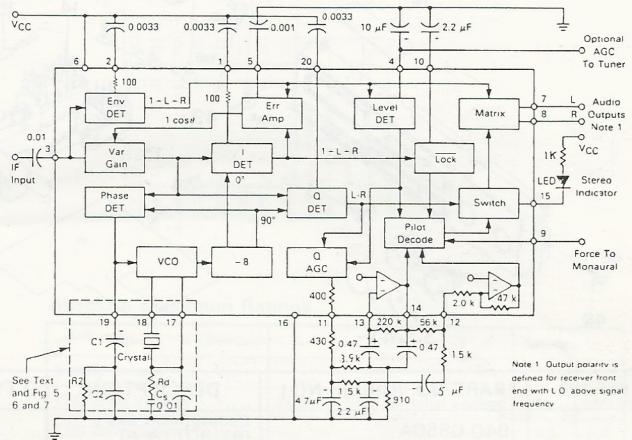


Fig. 3 – MOTOROLA CQUAM®



Envelope is compatible with existing monaural receivers.

Fig. 4 – BLOCK DIAGRAM



MOTOROLA CQUAM® – COMPATIBLE QUADRATURE AM STEREO

INTRODUCTION

In CQUAM®, conventional quadrature amplitude modulation has been modified by multiplying each axis by $\cos\theta$ as shown in Figures 2 and 3. The resulting carrier envelope is $1+L+R$, i.e., a correct sum signal for monaural receivers and for stereo receivers operating in monaural mode. A 25Hz pilot signal is added to the L-R information at a 4% modulation level.

THE DECODER

The MC13020P takes the output of the AM IF amplifier and performs the complete CQUAM® decoding function. In the absence of a good stereo signal, it produces an undegraded monaural output. Note in Figure 4 that the L+R information delivered to the output always comes from the envelope detector (Env DET).

The MC13020P decodes the stereo information by first converting the CQUAM® signal to QUAM, and then detecting QUAM. The conversion is accomplished by comparing the output of the Env DET and the I DET in the Err AMP. This provides the $1/\cos\theta$ correction factor, which is then multiplied by the CQUAM® incoming signal in the Var Gain block. Thus, the output of the Var Gain block is a QUAM signal, which can then be synchronously detected by conventional means. The I and Q detectors are held at 0° and 90° relative demodulation angles by reference signals from the phase-locked, divided-down VCO. The output of the I DET is $1-L+R$, with the added benefit (over the Env DET) of being able to produce a negative output on strong co-channel or noise interference. This is used to tell the Lock circuit to go to monaural operation. The output of the Q DET is the L-R and pilot information.

THE VCO

The VCO operates at 8 times the IF input frequency, which ensures that it is out-of-band, even when a 260kHz IF frequency is used. Typically a 450kHz IF frequency is used with synthesized front ends. This places the VCO at 3.6MHz, which permits economic crystal and ceramic resonators. A crystal VCO is very stable, but cannot be pulled very far to follow front-end mistuning. Pull-in capability of = Hz at 450kHz is typical, and de-Q-ing with a resistor (see Figure 7) can increase the range only slightly. Therefore, the crystal approach can only be used with very accurate, stable front-ends. By comparison, ceramic and L-C VCO circuits offer pull-in range in the order of = 2.5kHz (at 450kHz). Ceramic devices accurate enough to avoid trimming adjustment can be obtained with a matched capacitor for Cs (see Figures 1 and 5).

In the PLL filter circuit on Pin 19, C1 is the primary factor in setting a loop corner frequency of 8–10Hz, in-lock. An internally controlled fast pull-in is provided. R2 is selected to slightly overdamp the control loop, and C2 prevents high frequency instability.

The Level DET block senses carrier level and provides an optional tuner AGC source. It also operates on the Q AGC block to provide a constant amplitude of 25Hz pilot at Pin 11, and it delivers information to the pilot decoder regarding signal strength.

PILOT AND CO-CHANNEL FILTERS

The Q AGC output drives a low pass filter, made up of 400Ω internal, and 430Ω and $4.7\mu F$ external. From this point, an active 25Hz band-pass filter is coupled to the Pilot Decoder, Pin 14, and another low-pass filter is connected to the Co-channel Input, Pin 12. A 2:1 reduction of 25Hz pilot level to the Pilot Decode circuit will cause the system to go monaural, with the components shown. Refer to Figure 8 for the formulas governing the active band-pass filter. The co-channel input signal contains any low frequency intercarrier beat notes, and, at the selected level, prevents the Pilot Decode circuit from going into stereo. The co-channel input, Pin 12, gain can be adjusted by changing the external $1.5k$ resistor. The values shown set the "trip" level at about 7% modulation. The 25Hz pilot signal at the output of the active filter is opposite in phase to the pilot signal coming from the second low-pass filter. The $56k$ resistor from Pin 14 to Pin 12 causes the pilot to be cancelled at the co-channel input. This allows a more sensitive setting of the co-channel trip level.

THE PILOT DECODER

The Pilot Decoder has two modes of operation. When signal conditions are good, the decoder will switch to stereo after 7 consecutive cycles of the 25Hz pilot tone. When signal conditions are bad, the detected interference changes the pilot counter so as to require 37 consecutive cycles of pilot to go to stereo. In a frequency synthesized radio, the logic that mutes the audio when tuning can be connected to Pin 9. When this pin is held low it holds the decoder in monaural mode and switches it to the short count. This pin should be held low until the synthesizer and decoder have both locked onto a new station. A 300ms delay should be sufficient. If the synthesizer logic does not provide sufficient delay, the circuit shown in Figure 9 may be added. Once Pin 9 goes high, the Pilot Decoder starts counting. If no pilot is detected for seven consecutive counts, it is assumed to be a good monaural station and the decoder is switched to the long count. This reduces the possibility of false stereo triggering due to signal level fluctuation or noise. If the PLL goes out of lock, or interference is detected by the co-channel protection circuit before seven cycles are counted, the decoder goes into the long count mode. Each disturbance will reset the counter to zero. The Level Detector will keep the decoder from going into stereo if the IF input level drops $10dB$, but will not change the operation of the pilot counter.

Once the decoder has gone into the stereo mode, it will go instantly back to monaural if either the lock detector on Pin 10 goes low, or if the carrier level drops below the preset threshold. Seven consecutive counts of no pilot will also put the decoder in monaural. In stereo, the co-channel input is disabled, and co-channel or other noise is detected by negative excursions of the I DET, as mentioned earlier. When these excursions reach a level caused by approximately 20% modulation of co-channel, the lock detector puts the system in monaural, even though the PLL may still actually be locked. This higher level of co-channel tolerance provides the hysteresis to prevent chattering in and out of stereo on a marginal signal.

When all inputs to the Pilot Decode block are correct, and it has completed its count, it turns on the Switch, sending the L-R to the Matrix, and switches the pilot lamp pin to a low impedance to ground.

SUMMARY

It should be noted that in CQUAM®, with both channels AM modulated, the noise increase in stereo is a maximum of $3.0dB$, less on program material. Therefore, this is not the major concern in the choice of monaural to stereo switching point as it was in FM, and blend is not needed.

PIN DESCRIPTIONS

- Pin 1, 2 – Detector Filters, $R_{out} = 4.3k$, recommend $0.0033\mu F$ to Vcc to filter $450kHz$ components.
- Pin 3 – IF Signal Input.
- Pin 4 – Level Detector filter pin, $R_{out} = 8.2k$, $10\mu F$ to ground sets the AGC time constant. High impedance output, needs buffer.
- Pin 5 – Error Amp compensation to stabilize the Var Gain feedback loop.
- Pin 6 – Vcc 6–12Vdc, suitable for low Vbat automotive operation, but must be protected from "high line" condition.
- Pin 7, 8 – Left and Right Outputs, NPN emitter followers.
- Pin 9 – Forced Monaural, MOS or TTL controllable.
- Pin 10 – Lock detector filter, $R_{out} = 27k$, recommend $2.2\mu F$ to ground.
- Pin 11 – AGC'd Q output, NPN emitter follower with 400Ω from emitter to Pin 11.
- Pin 12 – Co-channel Input, $1.5k$ series in and $56k$ feedback.
- Pin 13 – Pilot Filter Input to op amp, see Figure 8.
- Pin 14 – Pilot Decode Input (op amp output) emitter follower, $R_{out} = 100\Omega$.
- Pin 15 – Stereo Lamp, open-collector of an NPN common emitter stage, can sink $50mA$, $V_{sat} = 0.3V$ at $5.0mA$.
- Pin 16 – Ground
- Pin 17 – Oscillator input, $R_{in} = 10k$, do not connect to Pin 18 or ground.
- Pin 18 – Oscillator feedback, NPN emitter, $R_{out} = 100\Omega$.
- Pin 19 – Phase Detector Output, current source to filter.
- Pin 20 – Detector Filter, $R_{out} = 4.3k$, recommend $0.0033\mu F$ to Vcc to filter $450kHz$.

Fig. 5 – CERAMIC VCO

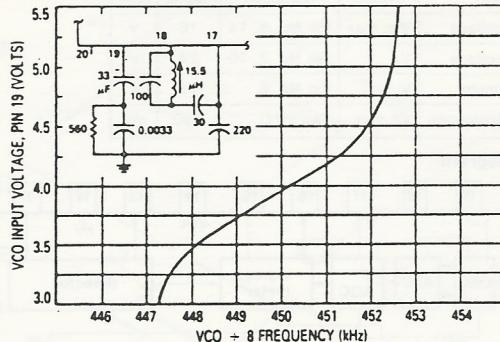
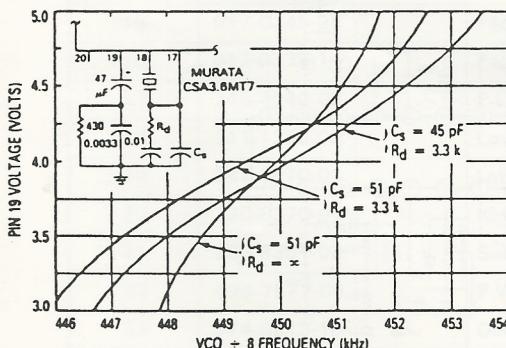


Fig. 7 – CRYSTAL VCO

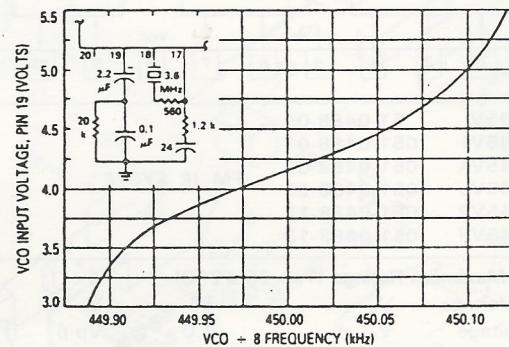
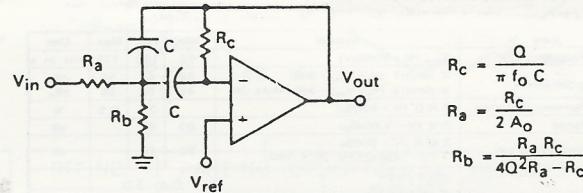


Fig. 8 – ACTIVE BAND-PASS FILTER



where, in this application

$$f_0 = \text{center frequency} = 25Hz$$

$$A_o = \text{gain at } f_0 \leq 35$$

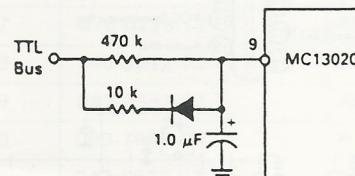
$$Q \leq 10$$

Choose values for f_0 , A_o , Q , and convenient C , solve for resistors

$C \pm 5\%$	$R_a \pm 5\%$	$R_b \pm 1\%$	$R_c \pm 1\%$
$0.47\mu F$	$3.9k$	910	$220k$
$0.33\mu F$	$6.8k$	$1.3k$	$330k$

Note: Capacitor C should be a good grade, low ESR.

Fig. 9 – FORCED MONAURAL OPTIONAL DELAY CIRCUIT

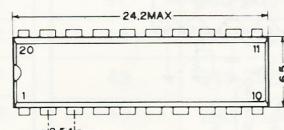


LA1135 051-0634-00
LA1135B 051-0634-01 AM Tuner

The part of electric specification is different between 051-0634-00 and 051-0634-01.

(Output level for signal meter output)

Outward Form

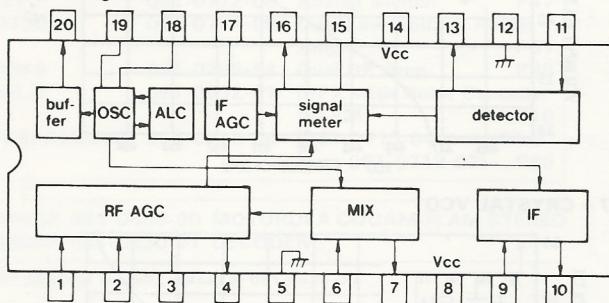


Performance

- MIX
- OSC (with ALC)
- IF amplification
- Detection
- AGC (Normal)
- RF wide bandwidth AGC
- Stop signal for auto search (Signal meter output)

Item	Symbol	Condition	Rating	Unit
Supply voltage	V _{cc} max	Pin No. 8, 14	16	V
Output voltage	V _o	Pin No. 7, 10	24	V
Input voltage	V _i	Pin No. 6	5.6	V
Power dissipation	V _d max	T _a ≤ 50°C	730	mV

Block Diagram



μPC1245V 51-0488-00

μPC1245V1 051-0488-01

■ μPC1245VK 051-0488-02

μPC1245VL 051-0488-03

μPC1245VP 051-0488-12

μPC1245VR 051-0488-13

FM IF SYSTE

Absolute Maximum Ratings (T_a = 25 ± 2°C)

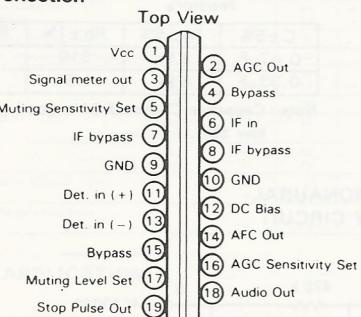
Supply Voltage	V _{cc}	16	V
Input Voltage	V _i	3.0	V _{p-p}
Power Dissipation	P _d (T _a = 75°C)	430	mW

Electrical Characteristics

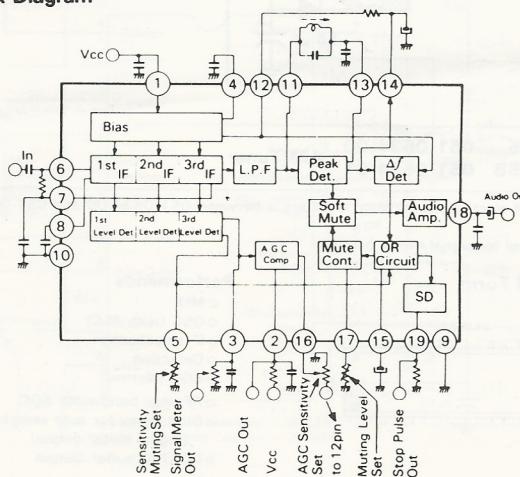
(T_a = 25 ± 3°C, V_{cc} = 10V, f = 10.7 MHz, RH ≤ 70%, f/M_{av} = 400Hz, Δf = ± 225kHz)

Item	Symbol	Min.	Typ.	Max.	Unit
Audio Frequency Out	V _{oaf} (V _i = 80dB _μ V)	85	130	175	mVr. m. s
Limiting Sensitivity	V _i (limit)1 (V _i = V _{oaf} - 3dB)	38	44	50	dB _μ
	V _i (limit)2 (V _i = V _{oaf} - 3dB, Mute ON)	42	50	58	dB _μ
Total Harmonic Distortion	T.H.D (V _i = 80dB _μ)		0.1	0.5	%
Signal/Noise	S/N (V _i = V _{oaf} dB _μ)	60	67		dB
A.M. Rejection Ration	A.M.R (V _i = 80dB _μ) (AM:400Hz, 30% mod)	30	42		dB
Signal Meter Drive Out	μPC1245V μPC1245V1 μPC1245VL μPC1245VP μPC1245VR	0.4 ~ 3.0			V
	(V _i = 60dB _μ)	0.95 ~ 1.3			
	μPC1245VP μPC1245VR	0.95 ~ 1.2			
		1.1 ~ 1.35			
A.G.C Out	V _{agc1} (V _i = 0dB _μ , V _{ia} = 3.0V) V _{agc2} (V _i = 100dB _μ , V _{ia} = 3.0V)	9.0	0.1	0.5	V
A.F.C Out	V _{afc} (V _i = 80dB _μ)	4.6	5.2	5.8	V

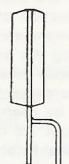
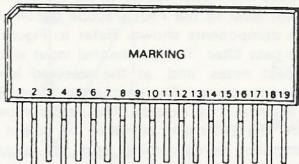
Terminal Connection



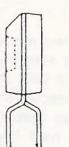
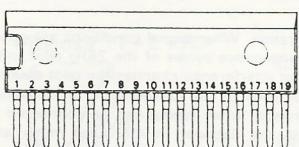
Block Diagram



μPC1245V (051-0488-00), μPC1245V1 (051-0488-01)

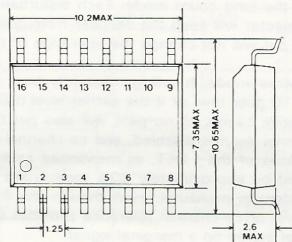


μPC1245VK (051-0488-02), μPC1245VL (051-0488-03)
μPC1245VP (051-0488-12), μPC1245VR (051-0488-13)



■ μPC1266G 051-0541-00 Diver Control SW.

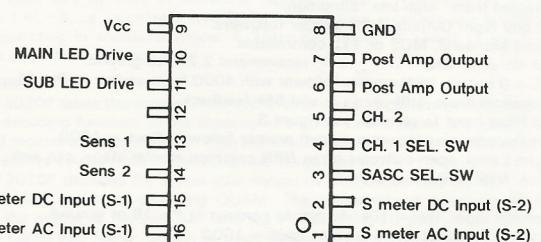
Outward Form



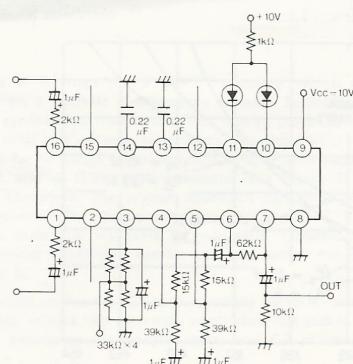
Absolute Maximum Ratings

Item	Symbol	Condition	Rating	Unit
Supply voltage	V _{cc}		16	V
LED drive voltage	V _{10.11}	10pin, 11pin Terminal voltage	16	V
LED drive current	I _{10.11}		40	mA
Power dissipation	P _d		250	mW

Terminal Connection

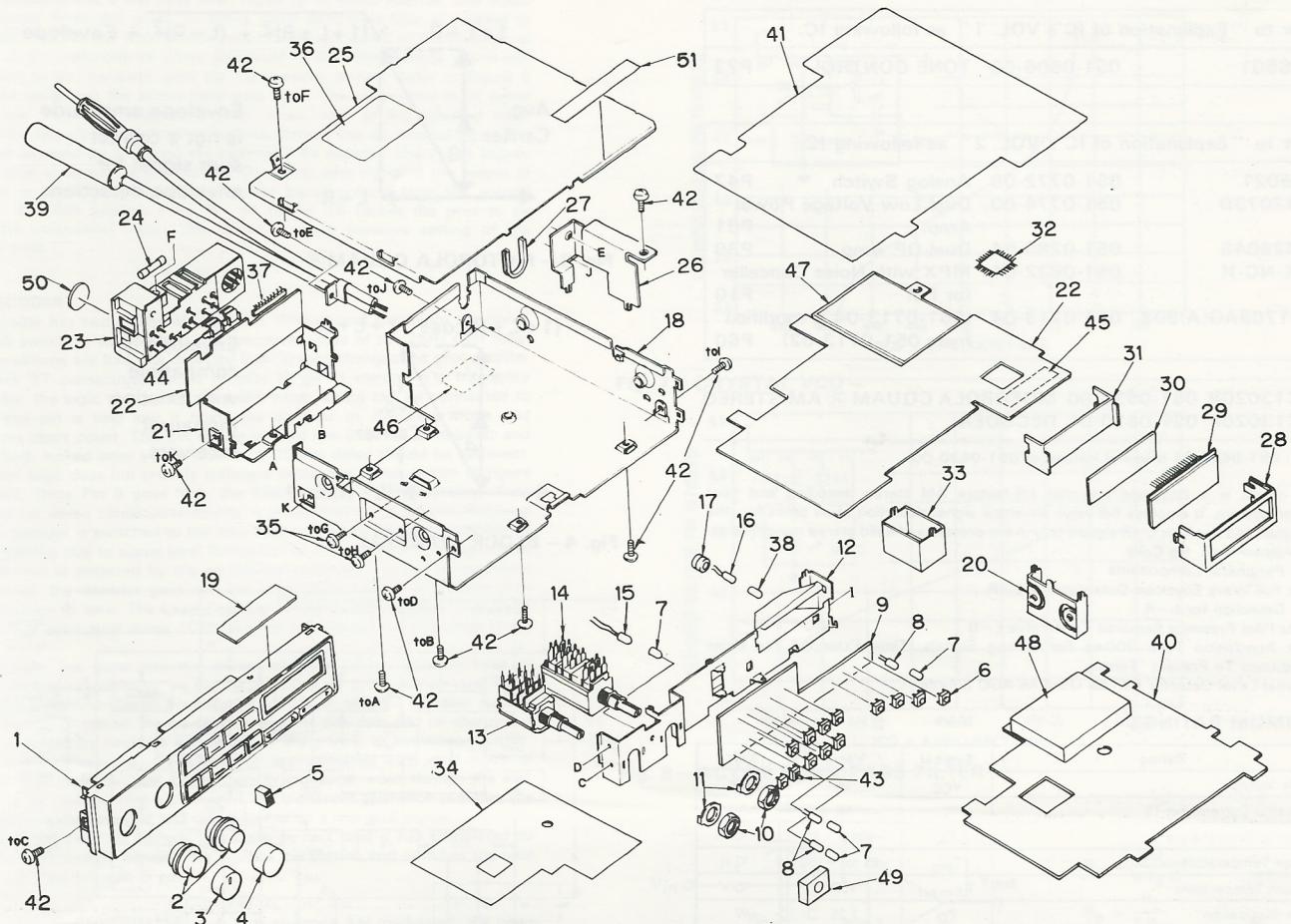


Equivalent Circuit



■ EXPLODED VIEW • PARTS LIST:

©Main section



REF. NO.	PART NO. (ORDER NO.)	DESCRIPTION	Q'TY
1	940-0850A	Escutcheon ass'y (RT-9071A-A)	1
	940-0849A	Escutcheon ass'y (RT-9071A-B)	
2	380-4646-01	Knob (BAL, FAD)	2
3	380-4635-05	Knob (VOL)	1
4	380-4634-01	Knob (BASS)	1
5	382-0970-03	Button (BW)	1
6	013-3694-00	Switch	12
7	345-3436-17	P.L cap	4
8	017-0345-17	Pilot lamp	3
9	099-7578-00	P.W.B	1
10	722-0231-00	Nut	2
11	745-0668-00	Washer	2
12	308-1041-01	Front cover	1
13	012-4319-00	Variable resistor (VOL)	1
14	012-4320-01	Variable resistor (BASS)	1
15	017-0345-35	Pilot lamp	1
16	017-0339-14	Pilot lamp	1
17	345-4040-02	P.L holder	1
18	311-1225-00	Lower case	1
19	347-1570-01	Label (RT-9071A-A)	1
20	330-8370-01	IC holder	1
21	330-8351-00	Socket holder	1
22	099-7577-05	P.W.B	1
23	074-0813-10	Outlet socket	1
24	120-0030-02	Fuse (3A)	1

REF. NO.	PART NO. (ORDER NO.)	DESCRIPTION	Q'TY
26	330-8371-01	Bracket	1
27	345-4191-00	Lead holder	1
28	335-1963-01	LCD cover	1
29	379-0082-00	Indicator	1
30	335-1964-02	Reflector	1
31	335-1965-01	LCD holder	1
32	051-0713-00	IC (μ PD1708G)	1
33	330-8372-00	Shield case	1
34	347-1939-00	Insulator	1
35	714-3004-80	Machine screw (M3x4)	2
36	286-5770-00	Set plate	1
37	076-0288-12	Plug	1
38	345-3842-02	P.L cap	1
39	092-0591-02	Antenna receptacle	1
40	099-7959-03	P.W.B	1
41	347-1938-02	Insulator	1
42	714-3004-80	Machine screw (M3x4)	12
43	013-3699-05	Switch	1
44	077-0083-00	Fuse receptacle	2
45	347-1172-01	Reflector	1
46	347-1195-00	Label	1
47	880-0004A	AM-ST TUNER PACK	1
48	941-0152-00	FM TUNER PACK	1
49	345-3904-00	Shade	1
50	290-3560-00	Label	1

OM (Oxidized Metal)	SS (Super Small)
S (Small)	TC (Temperature-Compensating)
HD (Higher Dielectric)	LL (Low Leak)
SC (Semi-Conductor)	USS (Ultra Super Small)

REF.NO.	PART NO.	DESCRIPTION	Q'TY
D501,502,504 D506,507,802 804~813 901	001-0330-00 (001-0294-00)	Diode 1SS119	17
	(001-0352-00)	Diode (1SS133)	
		Diode (1SS176)	
D902,903,904 905,907	001-0360-00 (001-0477-00)	Diode S5566B	5
		Diode (DSF10B)	
D807	001-0423-19 (001-0425-19)	Diode MA4056	1
		Diode (HZS5.6J)	
D201,202,801 906	001-0423-24 (001-0425-24)	Diode MA9041	4
		Diode (HZS9.1J)	
L902	009-0470-02	Choke	1
L901	009-0625-00	Choke	1
L202	010-2052-00	Coil	1
VR	012-4319-00	Variable resistor SW.VOL	1
VR	012-4320-01	Variable resistor B/T FAD	1
VR201	012-4431-02	Variable resistor 1kΩ	1
VR202	012-4431-09	Variable resistor 47kΩ	1
VR203	012-4431-10	Variable resistor 100kΩ	1
PL6	017-0339-14	Pilot lamp (BLK)	1
PL5	017-0345-35	Pilot lamp (YEL)	1
C207	042-0174-00	Electrolytic capacitor 16V4.7μF TAN	1
C211	042-0176-00	Electrolytic capacitor 16V10μF TAN	1
CCT1	050-0093-03	Component circuit 33kΩx9	1
IC201	051-0190-00	IC C-Z2	1
IC501	051-0606-00 (051-0606-50)	IC BT3S501	1
		IC (PA-S-0159)	
IC202	051-0651-00	IC C-Z2	1
IC801	051-0713-04	IC μPD1708AG(A)903	1
IC502	051-0772-00	IC TK15021	1
IC503	051-0774-00	IC NJM2073D	1
X801	061-1037-00	Crystal	1
Q802	100-1048-50 (100-1317-50)	Transistor 2SA1048Y,GR	1
		Transistor (2SA1317-STU)	
Q506	101-0911-00	Transistor 2SB911MPQR	1
Q801	102-1545-02	Transistor 2SC1545B	1
204,205,301 401,505,601 Q602,701,702 803,804,805 807,903	102-2458-50 (102-3330-50)	Transistor 2SC2458Y,GR,BL	14
		Transistor (2SC3330-STU)	
Q501,502	103-1504-05 (103-1450-20)	Transistor 2SD1504-E,TZ	2
		Transistor (2SD1450T)	
206,207,901 Q902,905,906 907	103-1225-50 (103-0973-50)	Transistor 2SD1225M-QR	7
		Transistor (2SD973A-RS)	

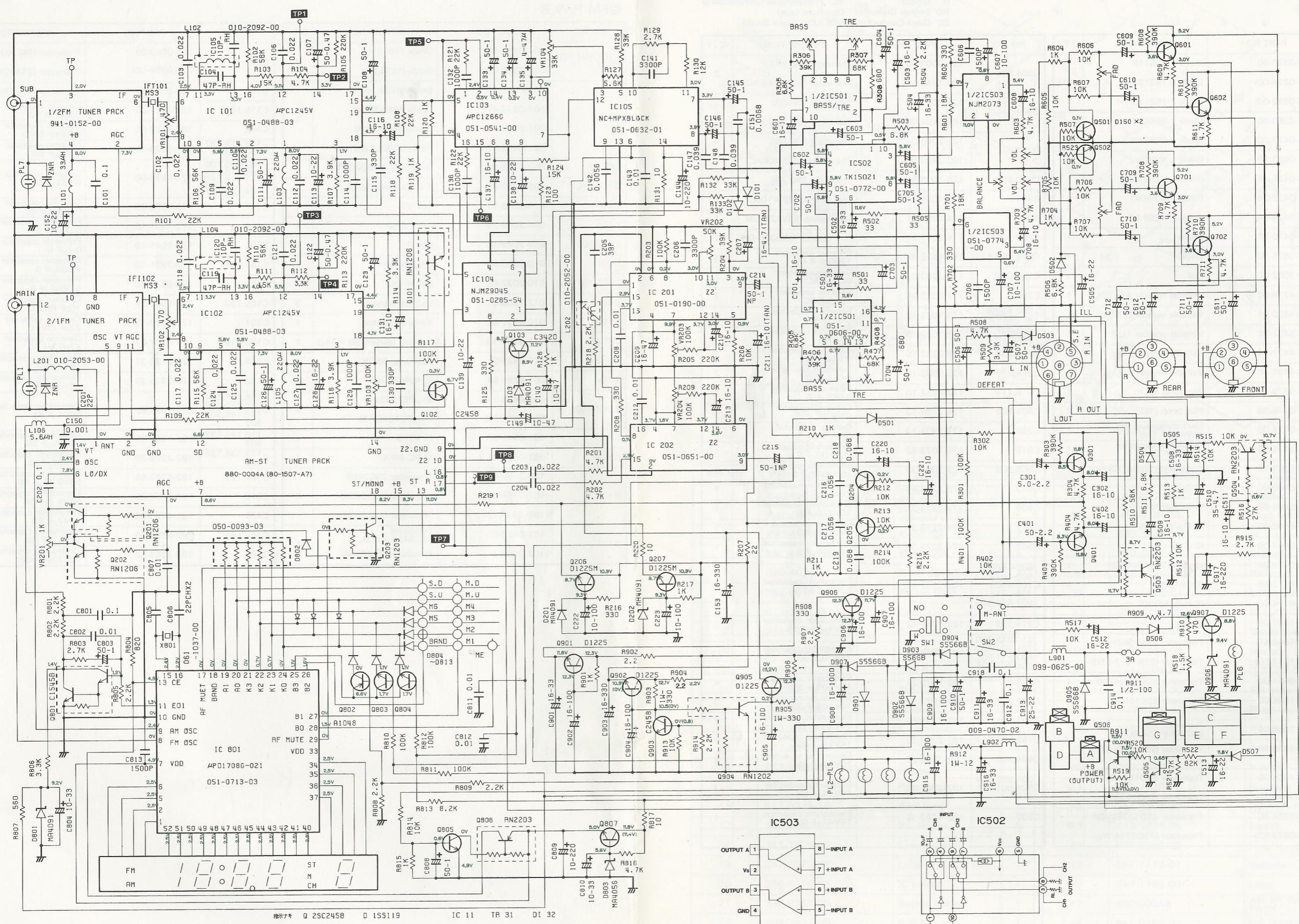
REF.NO.	PART NO.	DESCRIPTION	Q'TY
Q504,806	125-0003-03 (100-1346-00)	Transistor RN2203	2
Q904	125-2003-02 (102-3404-00)	Transistor RN1202	1
Q203	125-2003-03 (102-3400-00)	Transistor RN1203	1
Q201,202	125-2003-96	Transistor RN1206	2
R911	111-1011-82	Film resistor 1/2W100Ω	1
R912	114-1201-11	Film resistor 1W12Ω OM	1
R903,905	114-3311-11	Film resistor 1W330Ω OM	2
C606,706,813	160-1522-05	Ceramic capacitor 1500pF B HD	3
C208,212	171-1033-06	Ceramic capacitor 0.01μF SC	2
C206	171-3323-96	Ceramic capacitor 3300pF SC	1
C802,807,811 812	173-1032-10	Polyester capacitor 0.01μF S	4
C202,801,912 914,918	173-1042-10	Polyester capacitor 0.1μF S	5
C203,204	173-2232-10	Polyester capacitor 0.022μF S	2
C216,217	173-5632-10	Polyester capacitor 0.056μF S	2
C218,219	173-6832-10	Polyester capacitor 0.068μF S	2
C805,806	174-2209-13	Ceramic capacitor 22pF TC	2
C205	174-3909-13	Ceramic capacitor 39pF TC	1
C915	179-1073-33	Electrolytic capacitor 16V100μF S	1
C908,909	179-1083-33	Electrolytic capacitor 16V1000μF S	2
C913	179-2263-49	Electrolytic capacitor 25V22μF S	1
C809	179-2273-21	Electrolytic capacitor 10V220μF S	1
C917	179-2273-32	Electrolytic capacitor 16V220μF S	1
C903	179-3373-33	Electrolytic capacitor 16V330μF S	1
602~605 609~612 C702~705 709~712 803,808,910			Electrolytic capacitor 50V1μF SS
C214,215	182-1056-62	Electrolytic capacitor 50V1μF NP SS	2
210,213,220 C221,302,402 503,511,601 608,701,708			Electrolytic capacitor 16V10μF SS
C222,223,607 707	182-1063-32	Electrolytic capacitor 10V100μF SS	12
C902,904,905	182-1073-32	Electrolytic capacitor 16V100μF SS	3
C301,401	182-2253-69	Electrolytic capacitor 50V2.2μF SS	2
C153,505,512	182-2263-32	Electrolytic capacitor 16V22μF SS	3
C804,810	182-3363-29	Electrolytic capacitor 10V33μF SS	2
501,502,504 C508,901,911 916			Electrolytic capacitor 16V33μF SS
C209	182-4763-32	Electrolytic capacitor 16V47μF SS	1

◎FM P.W.B

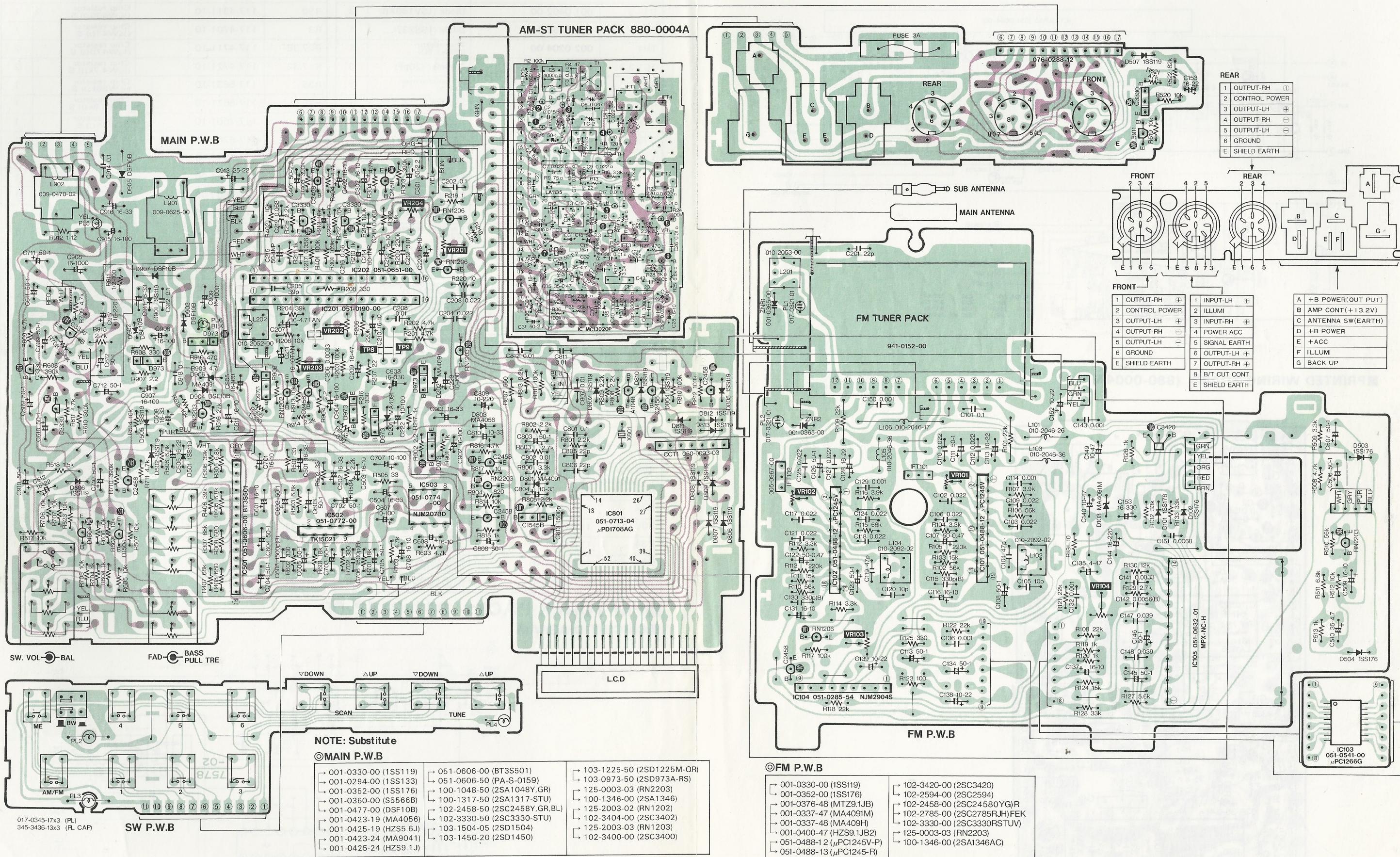
REF.NO.	PART NO.	DESCRIPTION	Q'TY
D _{101,102,503} 504	001-0330-00 (001-0352-00)	Diode 1SS119 Diode (1SS176)	4
D103	001-0376-48 (001-0337-47)	Diode MTZ9.1JB Diode (MA4091M)	1
	(001-0337-48)	Diode (MA4091H)	
	(001-0400-47)	Diode (HZN9.1JB2)	
ZNR1,2	001-0365-00	Diode ERZ-D03DK331	2
IFT101,102	005-0967-00	IF-transformer MS3L	2
L 106	010-2046-17	Coil VT	1
L 101	010-2046-26	Coil F-END	1
L 103,105	010-2046-36	Coil IF	2
L 201	010-2053-00	Coil AM-ANT	1
L 102,104	010-2092-02	Coil IF-DET	2
VR101,102	012-3808-01	Variable resistor	2
VR104	012-4431-08	Variable resistor	1
VR103	012-4431-10	Variable resistor SD 100kΩ	1
PL1,2	017-0321-01	Pilot lamp NEON	2
IC104	051-0285-54	IC NJM2904S	1
IC101,102 (051-0448-13)	051-0488-12	IC μPC1245V-P	2
		IC (μPC1245V-R)	
IC103	051-0541-00	IC V728	1
IC105	051-0632-01	IC NC-MPX	1
Q102	102-2458-00	Transistor 2SC2458	1
	(102-2785-10)	Transistor (2SC2785)	
	(102-3330-00)	Transistor (2SC3330)	
Q103	102-3420-00	Transistor 2SC3420-Y,G,BL	1
	(102-2594-00)	Transistor (2SC2594)	

REF.NO.	PART NO.	DESCRIPTION	Q'TY
Q503	125-0003-03 (100-0346-00)	Transistor RN2203 Transistor (2SA1346-AC)	1
Q101	125-2003-06	Transistor RN1206	1
C115,130	160-3312-05	Ceramic capacitor 330pF B HD	2
C142	160-5622-05	Ceramic capacitor 5600pF B HD	1
C _{114,129,132} 136,143	171-1023-06	Ceramic capacitor 1000pF SC	5
C _{102,103,106} C _{109,110,112} C _{117,118,121} C _{124,125,127}	171-2233-06	Ceramic capacitor 0.022μF SC	12
C141	171-3323-06	Ceramic capacitor 0.0033μF SC	1
C150	173-1021-10	Polyester capacitor 0.001μF S	1
C101	173-1041-19	Polyester capacitor 0.1μF S	1
C147,148	173-3931-10	Polyester capacitor 0.039μF S	2
C151	173-6821-10	Polyester capacitor 0.0068μF S	1
C105,120	174-1007-37	Ceramic capacitor 10pF RH TC	2
C201	174-2207-13	Ceramic capacitor 22pF CH TC	1
C103,119	174-4707-37	Ceramic capacitor 47pF RH TC	2
C144	179-2273-31	Electrolytic capacitor 16V220μF S	1
C153	179-3373-33	Electrolytic capacitor 16V330μF S	1
C _{108,111,123} C _{126,133,134} C _{145,146,506} 507	182-1053-69	Electrolytic capacitor 50V1μF SS	10
C _{116,131,137} 509	182-1063-39	Electrolytic capacitor 16V10μF SS	4
C _{113,138,139} 152	182-2263-29	Electrolytic capacitor 10V22μF SS	4
C107,122	182-4743-69	Electrolytic capacitor 50V0.47μF SS	2
C510	182-4753-59	Electrolytic capacitor 35V4.7μF SS	1
C135	182-4763-02	Electrolytic capacitor 4V47μF SS	1
C140,149	182-4763-29	Electrolytic capacitor 10V47μF SS	2
C128	183-2263-32	Electrolytic capacitor 16V22μF USS	1

■ CIRCUIT DIAGRAM:

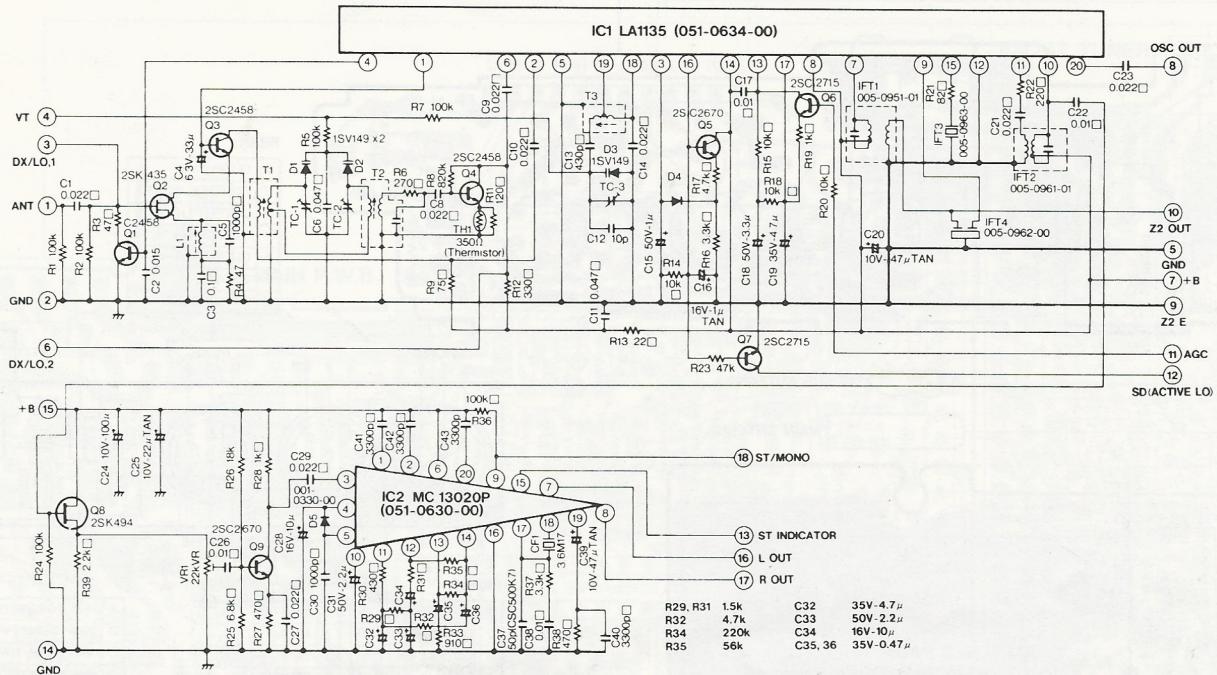


PRINTED WIRING BOARD:

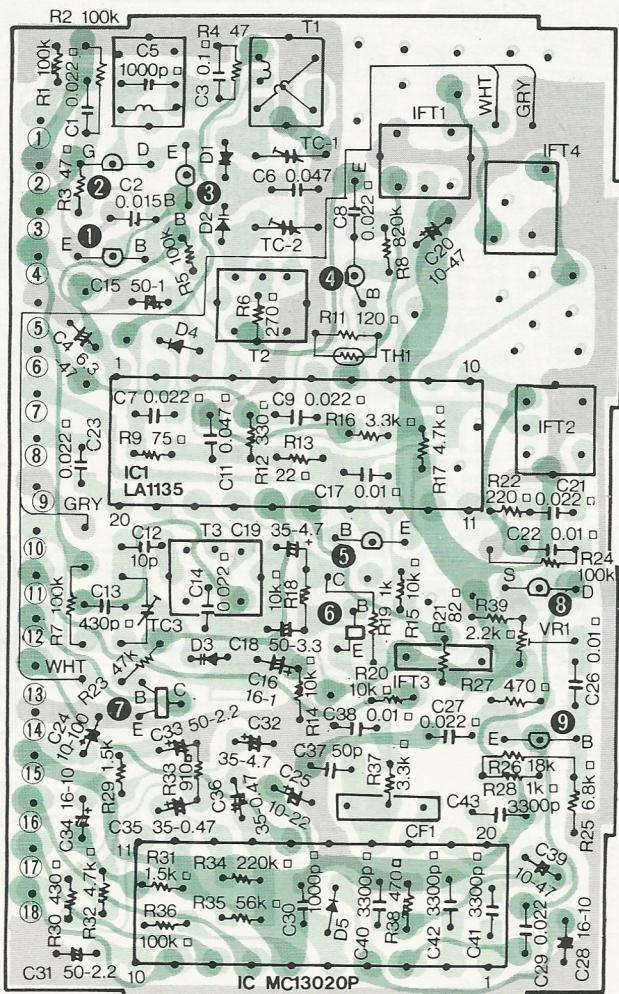


■ AM-ST TUNER PACK: 880-0004A

■ CIRCUIT DIAGRAM



■ PRINTED WIRING BOARD (880-0004A)



■ ELECTRICAL SECTION PARTS LIST (880-0004A)

REF.NO.	PART NO. (ORDER NO.)	DESCRIPTION	Q'TY	REF.NO.	PART NO. (ORDER NO.)	DESCRIPTION	Q'TY
D5	001-0330-00	Diode (1SS-119)	1	R16,37	117-3321-10	Chip resistor ($\frac{1}{16}W3.3k\Omega$) S	2
D1~3	001-0402-00	Diode (1SV149AB)	3	R30	117-4311-10	Chip resistor ($\frac{1}{16}W430\Omega$) S	1
D4	001-0453-00	Diode (1SS237)	1	R3	117-4701-10	Chip resistor ($\frac{1}{16}W47\Omega$) S	1
TH1	002-0204-00	Thermistor (350Ω TD)	1	R27,38	117-4711-10	Chip resistor ($\frac{1}{16}W470\Omega$) S	2
TC1,2,3	004-1567-00	Trimmer (20pF)	3	R17,32	117-4721-10	Chip resistor ($\frac{1}{16}W4.7k\Omega$) S	2
IFT1	005-0951-01	IF-transformer (IFT-1)	1	R35	117-5631-10	Chip resistor ($\frac{1}{16}W56k\Omega$) S	1
IFT2	005-0961-01	IF-transformer (IFT-2)	1	R25	117-6821-10	Chip resistor ($\frac{1}{16}W6.8k\Omega$) S	1
IFT4	005-0962-00	IF-transformer (10A)	1	R9	117-7501-10	Chip resistor ($\frac{1}{16}W75\Omega$) S	1
IFT3	005-0963-00	IF-transformer (BFU-450)	1	R21	117-8201-10	Chip resistor ($\frac{1}{16}W82\Omega$) S	1
T2	005-0973-00	IF-transformer (T-2 2ND)	1	R33	117-9111-10	Chip resistor ($\frac{1}{16}W910\Omega$) S	1
T1	010-2112-00	Coil (T-1 1ST)	1	C37	043-0204-00	Ceramic capacitor (50p)	1
L1	010-2113-00	Coil (L-1 5μH)	1	C2	171-1533-06	Ceramic capacitor (0.015μF) SC	1
T3	010-2114-00	Coil (T-3 OSC)	1	C43	173-3322-10	Ceramic capacitor (0.0033μF) S	1
VR1	012-3808-07	Variable resistor (22kΩ)	1	C12	174-1000-13	Ceramic capacitor (10pF CH) TC	1
IC2	051-0630-00	IC (MC13020P)	1	C13	176-4311-00	Ceramic chip capacitor (430pF CH) TC,S	1
IC1	051-0634-00	IC (LA1135)	1	C11	177-4732-05	Ceramic chip capacitor (0.047μF) HD	1
CF1	060-0112-00	Ceramic resonator (CSA3-6M17)	1	C5,30	178-1022-05	Ceramic chip capacitor (1000pF) HD,S	2
Q1,3,4	102-2458-25	Transistor (2SC2458Y)	3	C17,22,26 C38	178-1032-05	Ceramic chip capacitor (0.01μF) HD,S	4
Q5,9	102-2670-15	Transistor (2SC2670O)	2	C3	178-1045-06	Ceramic chip capacitor (0.1μF) HD,S	1
Q6,7	102-2715-15	Transistor (2SC2715-O)	2	C1,8,9,10,14 C21,23,27,29	178-2232-05	Ceramic chip capacitor (0.022μF) HD,S	9
Q2	108-0435-51	FET (2SK435-CD)	1	C40,41,42	178-3322-05	Ceramic chip capacitor (0.0033μF) HD,S	3
Q8	108-0494-02	FET (2SK494B)	1	C6	178-4735-06	Ceramic chip capacitor (0.047μF) HD,S	1
R28	117-1021-10	Chip resistor ($\frac{1}{16}W1k\Omega$) S	1	C25	042-0199-00	Electrolytic capacitor (10V22μF TAN)	1
R _{14,15,18}	117-1031-10	Chip resistor ($\frac{1}{16}W10k\Omega$) S	4	C20,39	042-0200-00	Electrolytic capacitor (10V47μF TAN)	2
R36	117-1041-10	Chip resistor ($\frac{1}{16}W100k\Omega$) S	1	C35,36	042-0230-00	Electrolytic capacitor (35V0.47μF TAN)	2
R11	117-1211-10	Chip resistor ($\frac{1}{16}W120\Omega$) S	1	C16	042-0239-00	Electrolytic capacitor (16V1μF TAN)	1
R29,31	117-1521-10	Chip resistor ($\frac{1}{16}W1.5k\Omega$) S	2	C15	182-1053-62	Electrolytic capacitor (50V1μF) SS	1
R13	117-2201-10	Chip resistor ($\frac{1}{16}W220\Omega$) S	1	C28,34	182-1063-32	Electrolytic capacitor (16V10μF) SS	2
R22	117-2211-10	Chip resistor ($\frac{1}{16}W220\Omega$) S	1	C24	182-1073-22	Electrolytic capacitor (10V100μF) SS	1
R39	117-2221-10	Chip resistor ($\frac{1}{16}W2.2k\Omega$) S	1	C31,33	182-2253-62	Electrolytic capacitor (50V2.2μF) SS	2
R34	117-2241-10	Chip resistor ($\frac{1}{16}W220k\Omega$) S	1	C18	182-3353-62	Electrolytic capacitor (50V3.3μF) SS	1
R6	117-2711-10	Chip resistor ($\frac{1}{16}W270\Omega$) S	1	C4	182-3363-12	Electrolytic capacitor (6.3V33μF) SS	1
R12	117-3311-10	Chip resistor ($\frac{1}{16}W330\Omega$) S	1	C19,32	182-4753-52	Electrolytic capacitor (35V4.7μF) SS	2

■ FM TUNER PACK: 941-0152-00

■ CIRCUIT DIAGRAM

